

## **Operational Amplifiers**

# SIGNATURE SERIES **Operational Amplifiers**

LM358xxx LM324xxx LM2904xxx LM2902xxx

## **General Description**

LM358xxx, LM324xxx, LM2904xxx, and LM2902xxx are monolithic IC's which integrate two or four independent op-amps on a single chip and feature high gain, low power consumption, and an operating voltage range of 3V to 36V (single power supply).

#### Features

- Operable with a single power supply
- Wide operating supply voltage range
- Input and output are operable GND sense
- Low supply current
- High open loop voltage gain
- Wide temperature range

## Application

- Current sense application
- Buffer application
- Active filter
- Consumer electronics

## **Pin Configuration**

: LM358DT
: LM358WDT
: LM2904DT
: LM2904WDT
: LM358PT
: LM358WPT
: LM2904PT
: LM2904WPT
: LM358ST
: LM2904ST

## **Key Specifications**

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	Operating Supply Voltage	
	Single Supply	+3V to +36V
	Dual Supply	±1.5V to ±18V
	Supply Current	
	LM358xxx/LM324xxx	0.7mA(Typ)
	LM2904xxx/LM2902xxx	0.7mA(Typ)
	Input Bias Current	20nA(Typ)
	Input Offset Current	2nA(Typ)
	Operating Temperature Range	
	LM358xxx/LM324xxx	-40°C to +85°C
	LM2904xxx/LM2902xxx	-40°C to +125°C

#### Packages

SO Package8 SO Package14 TSSOP8 TSSOP14 Mini SO8

W(Typ) x D(Typ) x H(Max) 4.90mm x 6.0mm x 1.55mm

8.65mm x 6.0mm x 1.55mm 3.00mm x 6.4mm x 1.10mm 5.00mm x 6.4mm x 1.10mm 3.00mm x 4.9mm x 0.95mm



OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays.

## **Pin Description**

Pin No.	Pin Name	Function
1	OUTPUT 1	CH1 OUTPUT
2	INVERTING INPUT 1	CH1 INVERTING INPUT
3	NON-INVERTING INPUT 1	CH1 NON-INVERTING INPUT
4	Vcc <sup>-</sup>	Negative power supply
5	NON-INVERTING INPUT 2	CH2 NON-INVERTING INPUT
6	INVERTING INPUT 2	CH2 INVERTING INPUT
7	OUTPUT 2	CH2 OUTPUT
8	Vcc <sup>+</sup>	Positive power supply

SO Package14	: LM324DT
(SOP-J14)	: LM324WDT
. ,	: LM2902DT
	: LM2902WDT
TSSOP14	: LM324PT
(TSSOP-B14J)	: LM2902PT

OUTPUT 1 1 14 OUTPUT 4 INVERTING INPUT 1 2 13 INVERTING INPUT 4 CH4 NON-INVERTING INPUT 1 3 12 NON-INVERTING INPUT 4 Vcc<sup>+</sup> 4 11 Vcc -NON-INVERTING INPUT 2 5 10 NON-INVERTING INPUT 3 INVERTING INPUT 2 6 9 INVERTING INPUT 3 ĒНŻ ĊНЗ OUTPUT 2 7 8 OUTPUT 3

## **Pin Description**

Pin No.	Pin Name	Function
1	OUTPUT1	CH1 OUTPUT
2	INVERTING INPUT 1	CH1 INVERTING INPUT
3	NON-INVERTING INPUT 1	CH1 NON-INVERTING INPUT
4	Vcc <sup>+</sup>	Positive power supply
5	NON-INVERTING INPUT 2	CH2 NON-INVERTING INPUT
6	INVERTING INPUT 2	CH2 INVERTING INPUT
7	OUTPUT 2	CH2 OUTPUT
8	OUTPUT3	CH3 OUTPUT
9	INVERTING INPUT 3	CH3 INVERTING INPUT
10	NON-INVERTING INPUT 3	CH3 NON-INVERTING INPUT
11	Vcc <sup>-</sup>	Negative power supply
12	NON-INVERTING INPUT 4	CH4 NON-INVERTING INPUT
13	INVERTING INPUT 4	CH4 INVERTING INPUT
14	OUTPUT 4	CH4 OUTPUT

## **Circuit Diagram**



Figure 1 Circuit Diagram (each Op-Amp)

## Absolute Maximum Ratings (Ta=25°C)

Parameter		Cumhal	Rating					
Parameter	Symbol		LM358xxx	LM324xxx	LM2904xxx	LM2902xxx	- Unit	
Supply Voltage	Vcc <sup>+</sup> -Vcc <sup>-</sup>			+:	36		V	
		SO Package8	0.67 (Note 1,6)	-	0.67 (Note 1,6)	-		
		TSSOP8	0.62 (Note 2,6)	-	0.62 (Note 2,6)	-		
Power Dissipation	Pd	Mini SO8	0.58 <sup>(Note 3,6)</sup>	-	0.58 (Note 3,6)	-	W	
		SO Package14	-	1.02 <sup>(Note 4,6)</sup>	-	1.02 (Note 4,6)	-	
		Mini SO8	-	0.84 (Note 5,6)	-	0.84 (Note 5,6)		
Differential Input Voltage (Note 7)		V <sub>ID</sub> 36					V	
Input Common-mode Voltage Range		V <sub>ICM</sub>	(Vcc <sup>-</sup> -0.3) to (Vcc <sup>-</sup> +36)					
Input Current (Note 8)		h	-10					
Operating Supply Voltage		V <sub>OPR</sub>			o +36.0 o ±18.0)		V	
Operating Temperature Range		T <sub>OPR</sub>	-40 to	o +85	-40 to	+125	°C	
Storage Temperature Range		T <sub>STG</sub>		-55 to	o +150		°C	
Maximum Junction Temperature		T <sub>JMAX</sub>		+1	50		°C	

Note: Absolute maximum rating item indicates the condition which must not be exceeded. Application if voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

(Note 1) To use at temperature above T<sub>A</sub>=25°C reduce 5.4mW.

(Note 2) To use at temperature above T<sub>A</sub>=25°C reduce 5.0mW

(Note 3) To use at temperature above T<sub>A</sub>=25°C reduce 4.7mW.

(Note 4) To use at temperature above  $T_A=25^{\circ}C$  reduce 8.2mW.

(Note 5) To use at temperature above  $T_A=25^{\circ}C$  reduce 6.8mW

(Note 6) Mounted on a FR4 glass epoxy PCB 70mm×70mm×1.6mm(Copper foil area less than 3%).

(Note 7) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than Vcc<sup>-</sup>.

(Note 8) An excessive input current will flow when input voltages of less than Vcc<sup>-</sup>-0.6V are applied.

The input current can be set to less than the rated current by adding a limiting resistor.

**Caution:** Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

## **Electrical Characteristics**

OLM358xxx (Unless otherwise specified, Vcc<sup>+</sup>=+5V, Vcc<sup>-</sup>=0V)

Parameter	Symbol	Temperature	Limit			Unit	Conditions	
		Range	Min.	Тур.	Max.			
Input Offset Voltage (Note 9)	V <sub>IO</sub>	25°C	—	2	7	mV	VO=1.4V,RS=0Ω 5V< Vcc <sup>+</sup> <30V	
	.10	Full Range	—	-	9		0 <vic< vcc<sup="">+-1.5V</vic<>	
Input Offset Current (Note 9)	I <sub>IO</sub>	25°C	-	2	30	nA	VO=1.4V	
	10	Full Range	—	-	100			
Input Bias Current (Note 9)	IB	25°C	—	20	150	nA	VO=1.4V	
	ы	Full Range	—	—	200	1173		
Large Signal Voltage Gain	Av	25°C	25	100	_	V/mV	Vcc <sup>+</sup> =15V VO=1.4V to 11.4V RL=2kΩ	
Currely Valtage Dais stien Datio		25°C	65	100	—		RS≦10kΩ	
Supply Voltage Rejection Ratio	PSRR	Full Range	65	_	_	dB	Vcc <sup>+</sup> =5V to 30V	
Supply Current		Full Dec	_	0.7	1.2	A	Vcc <sup>+</sup> =5V,No Load	
Supply Current	lcc	Full Range	_	-	2	mA	Vcc <sup>+</sup> =30V,No Load	
Input Common-mode Voltage		25°C	0	_	Vcc <sup>+</sup> -1.5	\ <i>\</i>	Vcc <sup>+</sup> =30V	
Range	VICM	Full Range	0	_	Vcc <sup>+</sup> -2.0	V	RS≦10kΩ	
Common-mode Rejection Ratio	01455	25°C	70	85	_	15		
	CMRR	Full Range	60	_	_	dB	RS≦10kΩ	
Output Source Current (Note 10)	I <sub>SOURCE</sub>	25°C	20	40	60	mA	Vcc <sup>+</sup> =15V,VO=+2V VID=+1V	
	I <sub>SINK</sub>		10	20	—	mA	VO=+2V, Vcc <sup>+</sup> =15V ,VID=-1V	
Output Sink Current <sup>(Note 10)</sup>		25°C	12	50	_	μA	VO=+0.2V, VC=+15V,VID=-1V	
	Vopp	25°C	_	_	Vcc <sup>+</sup> -1.5	.,		
Output Voltage Swing		Full Range	_	_	Vcc <sup>+</sup> -2.0	V	RL=2kΩ	
		25°C	27	28	_			
High Level Output Voltage	V <sub>он</sub>	Full Range	27	_	_	V	Vcc <sup>+</sup> =30V,RL=10kΩ	
		25°C	_	5	20			
Low Level Output Voltage	Vol	Full Range	_	_	20	mV	RL=10kΩ	
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL=2kΩ,CL=100pF, Vcc <sup>+</sup> =15V VI=0.5V to 3V, Unity Gain	
Gain Bandwidth Product	GBP	25°C	_	0.6	-	MHz	Vcc <sup>+</sup> =30V,RL=2kΩ, CL=100pF VIN=10mV,f=100kH	
Total Harmonic Distortion	THD	25°C	_	0.02	_	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF,VO=2Vp	
Input Equivalent Noise Voltage	V <sub>N</sub>	25°C	_	40	_	nV/√Hz	f=1kHz,RS=100Ω Vcc <sup>+</sup> =30V	
Input Offset Voltage Drift (Note 9)	$\Delta V_{IO} / \Delta T$	_	_	7	-	µV/°C	_	
Input Offset Current Drift (Note 9)	$\Delta I_{IO} / \Delta T$	_	_	10	_	pA/°C	-	
	-			1	1	•	1kHz≦f≦20kHz	

(Note 10) Under high temperatures, please consider the power dissipation when selecting the output current. When output terminal is continuously shorted the output current reduces the internal temperature by flushing.

## **Electrical Characteristics - continued**

OLM324xxx (Unless otherwise specified, Vcc<sup>+</sup>=+5V, Vcc<sup>-</sup>=0V)

Parameter	Symbol	Temperature Range	Min.	Limit Typ.	Max.	Unit	Conditions	
		25°C	_		7		VO=1.4V,RS=0Ω	
Input Offset Voltage <sup>(Note 11)</sup>	V <sub>IO</sub>	Full Range	_	_	9	mV	5V< Vcc <sup>+</sup> <30V 0 <vic< vcc<sup="">+-1.5V</vic<>	
Input Offset Current (Note 11)		25°C	_	2	30	- 0		
input Onset Current	lio	Full Range	—	_	100	nA	VO=1.4V	
Input Bias Current (Note 11)	IB	25°C	_	20	150	nA	VO=1.4V	
	чв	Full Range	—	—	300		-	
Large Signal Voltage Gain	Av	25°C	25	100	_	V/mV	Vcc <sup>+</sup> =15V VO=1.4V to 11.4V RL=2kΩ	
Supply Voltage Rejection Ratio	PSRR	25°C	65	110	—	dB	RS≦10kΩ	
	T SIXIX	Full Range	65	—	—	uв	Vcc <sup>+</sup> =5V to 30V	
		25°C	—	0.7	1.2		Vcc <sup>+</sup> =5V,No Load	
Supply Current	1	25°C	_	1.5	3	<b>~</b> ^	Vcc <sup>+</sup> =30V,No Load	
Supply Current	I <sub>CC</sub>	Full Range	_	0.8	1.2	mA	Vcc <sup>+</sup> =5V,No Load	
		Full Range	—	1.5	3	1	Vcc <sup>+</sup> =30V,No Load	
Input Common-mode Voltage	V	25°C	0	_	Vcc <sup>+</sup> -1.5	V	Vcc <sup>+</sup> =30V	
Range	VICM	Full Range	0	_	Vcc <sup>+</sup> -2.0	V	VCC = 30 V	
Common-mode Rejection Ratio	CMRR	25°C	70	80	—	dB	RS≦10kΩ	
	CIVIRR	Full Range	60	_	_	uв		
Output Source Current (Note 12)	ISOURCE	25°C	20	40	70	mA	Vcc <sup>+</sup> =15V,VO=+2V VID=+1V	
()   ++ (2)			10	20	_	mA	VO=+2V, Vcc <sup>+</sup> =15V,VID=-1V	
Output Sink Current <sup>(Note 12)</sup>	ISINK	25°C	12	50	_	μA	VO=+0.2V, Vcc <sup>+</sup> =15V ,VID=-1V	
	1/2.2.2	25°C	_	_	Vcc <sup>+</sup> -1.5			
Output Voltage Swing	Vopp	Full Range	_	_	Vcc <sup>+</sup> -2.0	V	RL=2kΩ	
High Level Output Voltage	V <sub>он</sub>	25°C	27	28	_	V	Vcc <sup>+</sup> =30V,RL=10kΩ	
nigh Level Output voltage	VOH	Full Range	27	_	_	v	VCC = 30 V, KL = 10KS	
Low Level Output Voltage	V <sub>OL</sub>	25°C	—	5	20	mV	RL=10kΩ	
Lon Lovor Output Voltago	¥ UL	Full Range	_		20			
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL=2kΩ,CL=100pF Vcc <sup>+</sup> =15V VI=0.5V to 3V, Unity Gain	
Gain Bandwidth Product	GBP	25°C	_	0.6	_	MHz	Vcc <sup>+</sup> =30V,RL=2kΩ, CL=100pF VIN=10mV,f=100kF	
Total Harmonic Distortion	THD	25°C	_	0.015	-	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF,VO=2Vp	
Input Equivalent Noise Voltage	$V_{N}$	25°C	_	40	-	nV/√Hz	f=1kHz,RS=100Ω Vcc <sup>+</sup> =30V	
Input Offset Voltage Drift (Note 11)	$\Delta V_{IO} / \Delta T$	_	_	7	_	µV/°C	—	
Input Offset Current Drift (Note 11)	$\Delta I_{IO} / \Delta T$	_	_	10	_	pA/°C	_	
Channel Separation	CS	25°C		120	_	dB	1kHz≦f≦20kHz	

(Note 11) Absolute value

(Note 12) Under high temperatures, please consider the power dissipation when selecting the output current.

When output terminal is continuously shorted the output current reduces the internal temperature by flushing.

## **Electrical Characteristics - continued**

OLM2904xxx (Unless otherwise specified, Vcc<sup>+</sup>=+5V, Vcc<sup>-</sup>=0V)

Parameter	Symbol	Temperature		Limit			Conditions	
	,	Range	Min.	Тур.	Max.	Unit		
Input Offset Voltage (Note 13)	V <sub>IO</sub>	25°C	_	2	7	mV	VO=1.4V	
		Full Range	—	-	9			
Input Offset Current (Note 13)	I <sub>IO</sub>	25°C	—	2	50	nA	VO=1.4V	
		Full Range	—	-	200			
Input Bias Current (Note 13)	Ι <sub>Β</sub>	25°C	—	20	150	nA	VO=1.4V	
		Full Range	-	-	200		Vcc <sup>+</sup> =15V	
Large Signal Voltage Gain	Av	25°C	25	100	_	V/mV	VCC =15V VO=1.4V to 11.4V RL=2kΩ	
Supply Voltage Rejection Ratio	PSRR	25°C	65	100	_	dB	RS≦10kΩ	
Supply Voltage Rejection Ratio	FORK	Full Range	65	-	—	uБ	Vcc <sup>+</sup> =5V to 30V	
Supply Current		25°C	—	0.7	1.2	~^^	Vcc <sup>+</sup> =5V,No Load	
Supply Current	Icc	Full Range	—	-	2	mA	VCC = 5 V, NO LOAU	
Input Common-mode Voltage	V	25°C	0	_	Vcc <sup>+</sup> -1.5	V	$1/22^{+}$ 201/	
Range	VICM	Full Range	0	-	Vcc <sup>+</sup> -2.0	v	Vcc <sup>+</sup> =30V	
Common mode Dejection Datio	CMDD	25°C	70	85	_	٩D	RS=10kΩ	
Common-mode Rejection Ratio	CMRR	Full Range	60	-	_	dB		
Output Source Current (Note 14)	ISOURCE	25°C	20	40	60	mA	Vcc <sup>+</sup> =+15V,VO=+2V VID=+1V	
Output Sink Current (Note 14)	I <sub>SINK</sub>	25°C	10	20	-	mA	VO=2V,Vcc <sup>+</sup> =+5V VID=-1V	
		23 0	12	50	-	μA	VO=+0.2V, Vcc <sup>+</sup> =+15V ,VID=-1	
Output Voltage Swing	Vopp	25°C	—	—	Vcc <sup>+</sup> -1.5	v	RL=2kΩ	
	VOPP	Full Range	—	-	Vcc <sup>+</sup> -2.0	· · · ·		
High Level Output Voltage	Vон	25°C	27	-	—	V	Vcc <sup>+</sup> =30V,RL=10kΩ	
nigh Level Output Voltage	V OH	Full Range	27	28	—	• •	VCC = 50 V, IVE = 10K	
Low Level Output Voltage	V <sub>OL</sub>	25°C	_	5	20	mV		
Low Level Output Voltage	VOL	Full Range	—	—	20	111 V	RL=10kΩ	
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL= $2k\Omega$ ,CL=100pF Unity Gain VI=0.5V to 3V Vcc <sup>+</sup> =15V	
Gain Bandwidth Product	GBP	25°C	_	0.6	_	MHz	Vcc <sup>+</sup> =30V,RL=2kΩ CL=100pF VIN=10mV	
Total Harmonic Distortion	THD	25°C	_	0.02	_	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF, Vcc <sup>+</sup> =30V,VO=2Vp	
Input Equivalent Noise Voltage	V <sub>N</sub>	25°C	_	40	_	nV/√Hz	f=1kHz,RS=100Ω Vcc <sup>+</sup> =30V	
Input Offset Voltage Drift (Note 13)	$\Delta V_{IO} / \Delta T$	_	_	7	-	µV/°C	-	
	1			1	1			
Input Offset Current Drift (Note 13)	$\Delta I_{IO} / \Delta T$	—	_	10	-	pA/°C	-	

(Note 13) Absolute value

(Note 14) Under high temperatures, please consider the power dissipation when selecting the output current.

When the output terminal is continuously shorted the output current reduces the internal temperature by flushing.

## **Electrical Characteristics - continued**

OLM2902xxx (Unless otherwise specified, Vcc<sup>+</sup>=+5V, Vcc<sup>-</sup>=0V)

Parameter Sy		Temperature Range	Min.	Limit Typ.	Max.	Unit	Conditions	
Incruit Official Violtering (Note 15)	V	25°C	_	2	7		VO 4 4V	
Input Offset Voltage (Note 15)	V <sub>IO</sub>	Full Range	_	_	9	mV	VO=1.4V	
Input Offset Current (Note 15)	I <sub>IO</sub>	25°C	_	2	30	nA	VO=1.4V	
		Full Range	_	-	200			
Input Bias Current (Note 15)	IB	25°C		20	150	nA	VO=1.4V	
Large Signal Voltage Gain	Av	Full Range 25°C			Vcc <sup>+</sup> =15V VO=1.4V to 11.4V RL=2kΩ			
Supply Voltage Rejection Ratio	PSRR	25°C	65	110	_	dB	RS≦10kΩ	
	I SIXIX	Full Range	65	_	—	uв	Vcc <sup>+</sup> =5V to 30V	
		25°C	_	0.7	1.2		Vcc <sup>+</sup> =5V,No Load	
		25°C	_	1.5	3		Vcc <sup>+</sup> =30V,No Load	
Supply Current	Icc	Full Range	_	0.8	1.2	mA	Vcc <sup>+</sup> =5V,No Load	
		Full Range	_	1.5	3		Vcc <sup>+</sup> =30V,No Load	
Input Common-mode Voltage		25°C	0	_	Vcc <sup>+</sup> -1.5	N/	\/ <sup>+</sup> 00\/	
Range	VICM	Full Range	0	_	Vcc <sup>+</sup> -2.0	V	Vcc <sup>+</sup> =30V	
Common mode Dejection Detie		25°C	70	80	—	٦D	RS=10kΩ	
Common-mode Rejection Ratio	CMRR	Full Range	60	_	—	dB		
Output Source Current (Note 16)	ISOURCE	25°C	20	40	70	mA	Vcc <sup>+</sup> =+15V,VO=+2V VID=+1V	
Output Sink Current (Note 16)	I <sub>SINK</sub>	25°C	10	20	_	mA	VO=2V,Vcc <sup>+</sup> =+5V VID=-1V	
ouput on k ourient		25 0	12	50	_	μA	VO=+0.2V, Vcc <sup>+</sup> =+15V ,VID=-1\	
Output Voltage Swing	Vann	25°C	_	-	Vcc <sup>+</sup> -1.5	V	RL=2kΩ	
Output voltage Swing	Vopp	Full Range	_	—	Vcc <sup>+</sup> -2.0	V		
High Level Output Voltage	V <sub>OH</sub>	25°C	27	28	_	V	Vcc <sup>+</sup> =30V,RL=10kΩ	
Thigh Level Output Voltage	V OH	Full Range	27	—	—	v	VCC = 50 V, IVE = 10K22	
Low Level Output Voltage	V <sub>OL</sub>	25°C	—	5	20	mV	RL=10kΩ	
	VOL	Full Range	_	_	20			
Slew Rate	SR	25°C	_	0.3	-	V/µs	RL=2kΩ,CL=100pF, Unity Gain VI=0.5V to 3V Vcc <sup>+</sup> =15V	
Gain Bandwidth Product	GBP	25°C	_	0.3	-	MHz	Vcc <sup>+</sup> =30V,RL=2kΩ CL=100pF VIN=10mV f=1kHz,AV=20dB	
Total Harmonic Distortion	THD	25°C	-	0.015	-	%	RL=2kΩ CL=100pF, Vcc <sup>+</sup> =30V,VO=2Vpp	
Input Equivalent Noise Voltage	V <sub>N</sub>	25°C	_	40	-	nV/√Hz	f=1kHz,RS=100Ω Vcc <sup>+</sup> =30V	
Input Offset Voltage Drift (Note 15)	$\Delta V_{IO} / \Delta T$	_	_	7	_	µV/°C	-	
Input Offset Current Drift (Note 15)	$\Delta I_{IO} / \Delta T$	_	_	10	_	pA/°C	-	
Channel Separation	CS	25°C	_	120	_	dB	1kHz≦f≦20kHz	

(Note 16) Under high temperatures, please consider the power dissipation when selecting the output current.

When the output terminal is continuously shorted the output current reduces the internal temperature by flushing.

#### **Description of Electrical Characteristics**

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

#### 1. Absolute maximum ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

- (1) Supply Voltage (Vcc<sup>+</sup>/ Vcc<sup>-</sup>) Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.
- (2) Differential Input Voltage (V<sub>ID</sub>) Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging the IC.
- (3) Input Common-mode Voltage Range (V<sub>ICM</sub>) Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.
- (4) Operating and storage temperature ranges (Topr,Tstg) The operating temperature range indicates the temperature range within which the IC can operate. The higher the ambient temperature, the lower the power consumption of the IC. The storage temperature range denotes the range of temperatures the IC can be stored under without causing excessive deterioration of the electrical characteristics.
- (5) Power dissipation (P<sub>D</sub>) Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, Pd is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

#### 2. Electrical characteristics

- Input Offset Voltage (V<sub>IO</sub>)
   Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.
- (2) Input Offset Voltage drift (△V<sub>IO</sub> /△T) Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.
- (3) Input Offset Current (I<sub>IO</sub>)
   Indicates the difference of input bias current between the non-inverting and inverting terminals.
- (4) Input Offset Current Drift (△lio/△T)
   Signifies the ratio of the input offset current fluctuation to the ambient temperature fluctuation.
- (5) Input Bias Current (I<sub>B</sub>) Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.
- (6) Supply Current (ICC) Indicates the current that flows within the IC under specified no-load conditions.
- (7) Maximum Output Voltage(High) / Maximum Output Voltage(Low) (VOH/VOL) Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.
- (8) Large Signal Voltage Gain (Av) Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage. Av = (Output voltage) / (Differential Input voltage)
- (9) Input Common-mode Voltage Range (V<sub>ICM</sub>) Indicates the input voltage range where IC normally operates.

- (10) Common-mode Rejection Ratio (CMRR)
   Indicates the ratio of fluctuation of input offset voltage when the input common mode voltage is changed. It is
   normally the fluctuation of DC.
   CMRR = (Change of Input common-mode voltage)/(Input offset fluctuation)
- Power Supply Rejection Ratio (PSRR)
   Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC.
   PSRR= (Change of power supply voltage)/(Input offset fluctuation)
- (12) Output Source Current/ Output Sink Current (I<sub>source</sub> / I<sub>sink</sub>) The maximum current that can be output from the IC under specific output conditions. The output source current indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC. indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC.
- (13) Channel Separation (CS) Indicates the fluctuation in the output voltage of the driven channel with reference to the change of output voltage of the channel which is not driven.
- (14) Slew Rate (SR) Indicates the ratio of the change in output voltage with time when a step input signal is applied.
- (15) Gain Bandwidth (GBW)
   The product of the open-loop voltage gain and the frequency at which the voltage gain decreases 6dB/octave.
- (16) Input Referred Noise Voltage (V<sub>N</sub>) Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal.

## **Typical Performance Curves**

OLM358xxx, LM2904xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +70°C LM2904 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

OLM324xxx, LM2902xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

#### O LM324xxx, LM2902xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

O LM324xxx, LM2902xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

#### OLM324xxx, LM2902xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

#### OLM324xxx, LM2902xxx



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C



(\*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

## Application Information

Measurement Circuit 1 NULL Method Measurement Condition

Parameter	VF	S1	S2	S3	Vcc <sup>+</sup>	Vcc <sup>-</sup>	EK	Vicm	Calculation
Input Offset Voltage	VF1	ON	ON	OFF	5 to 30	0	-1.4	0	1
Input Offset Current	VF2	OFF	OFF	OFF	5	0	-1.4	0	2
Input Bias Current	VF3	OFF	ON	OFF	5	0	-1.4	0	3
	VF4	ON	OFF	OFF	5	0	-1.4	0	3
Larga Signal Valtaga Cain	VF5	- ON	ON	ON	15	0	-1.4	0	4
Large Signal Voltage Gain	VF6			ON	15	0	-11.4	0	4
Common mode Dejection Datio	VF7	ON	ON	OFF	5	0	-1.4	0	5
Common-mode Rejection Ratio	VF8	ON	ON	OFF	5	0	-1.4	3.5	5
Supply Voltage Rejection Ratio	VF9	ON		OFF	5	0	-1.4	0	C
	VF10	UN	ON	OFF	30	0	-1.4	0	6

-Calculation-

1. Input Offset Voltage (Vio)

$$V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S} [V]$$

2. Input Offset Current (lio)

 $I_{IO} = \frac{|V_{F2}-V_{F1}|}{R_{I} \times (1+R_{F}/R_{S})}$  [A]

 $|V_{F4}-V_{F3}|$ 

 $2 \times R_I \times (1 + R_F/R_S)$ 

 $A_V = 20Log \quad \frac{10 \times (1+R_F/R_S)}{|V_{F5}-V_{F6}|} \quad [dB]$ 

[A]

3. Input Bias Current (Ib)

4.	Large	Signal	Voltage	Gain	(Av)	
----	-------	--------	---------	------	------	--

5. Common-mode Rejection Ration (CMRR)  $CMRR = 20Log \frac{3.5 \times (1+R_F/R_S)}{|V_{F8}-V_{F7}|}$  [dB]

 $I_B =$ 

. . . .

PSRR=20Log 
$$\frac{25 \times (1 + R_F/R_S)}{|V_{F10} - V_{F9}|}$$
 [dB]

6. Power supply rejection ratio (PSRR)



Figure . 50 Test circuit1 (one channel only)

#### **Measurement Circuit2 Switch Condition**

SW No.	SW 1	SW 2	SW 3	SW 4	SW 5	SW 6	SW 7	SW 8	SW 9	SW 10	SW 11	SW 12	SW 13	SW 14	SW 15
Supply Current	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF
High level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Low level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Output source current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Output sink current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF	OFF
Gain band width product	OFF	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF
Equivalent input noise voltage	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF



Figure 51 Measurement circuit2 (Each Op-Amps)









## **Examples of circuit**

OVoltage follower



Voltage gain is 0 dB.

This circuit controls output voltage (OUT) equal input voltage (IN), and keeps OUT with stable because of high input impedance and low output impedance. OUT is shown next formula. OUT=IN

OInverting amplifier



For inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase reversed voltage is output.

OUT is shown next formula. OUT=-(R2/R1) • IN Input impedance is R1.

ONon-inverting amplifier



For non-inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase is same with IN. OUT is shown next formula.  $OUT= (1+R2/R1) \cdot IN$ 

This circuit realizes high input impedance because Input impedance is operational amplifier's input Impedance.

#### **Power Dissipation**

Power dissipation (total loss) indicates the power that the IC can consume at  $T_A=25^{\circ}C$  (normal temperature). As the IC consumes power, it heats up, causing its temperature to be higher than the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol  $\theta_{JA}$ °C/W, indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

Figure 54(a) shows the model of the thermal resistance of a package. The equation below shows how to compute for the Thermal resistance ( $\theta_{JA}$ ), given the ambient temperature ( $T_A$ ), maximum junction temperature ( $T_{Jmax}$ ), and power dissipation ( $P_D$ ).

$$\theta_{JA} = (T_{Jmax} - T_A) / P_D \circ C/W$$

The derating curve in Figure 54(b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance ( $\theta_{JA}$ ), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 54(c), (d) shows an example of the derating curve for LM358xxx, LM2904xxx, LM324xxx and LM2902xxx.



 (Note 17)
 (Note 18)
 (Note 19)
 (Note 20)
 (Note 21)
 Unit

 6.2
 5.4
 5.0
 8.2
 7.0
 mW/°C

Figure 54 Derating Curves

## **Operational Notes**

## 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

## 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## **Operational Notes – continued**

#### 11. Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



#### 12. Unused Circuits

When there are unused circuits it is recommended that they be connected as in Figure 104, setting the non-inverting input terminal to a potential within the in-phase input voltage range ( $V_{ICM}$ ).



Figure 56. Disable Circuit Example

#### 13. Input Terminal Voltage

Applying  $Vcc^{-} + 36V$  to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

#### 14. Power Supply (signal / dual)

The op-amp operates when the specified voltage supplied is between Vcc<sup>+</sup> and Vcc<sup>-</sup>. Therefore, the single supply op-amp can be used as a dual supply op-amp as well.

#### 15. Terminal short-circuits

When the output and Vcc<sup>+</sup> terminals are shorted, excessive output current may flow, resulting in undue heat generation and, subsequently, destruction.

#### 16. IC Handling

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations in the electrical characteristics due to piezo resistance effects.

#### 17. Output Capacitor

If a large capacitor is connected between the output pin and Vcc<sup>-</sup> pin, current from the charged capacitor will flow into the output pin and may destroy the IC when the Vcc<sup>+</sup> pin is shorted to ground or pulled down to 0V. Use a capacitor smaller than  $0.1 \mu$ F between output pin and Vcc<sup>-</sup> pin.





## Physical Dimension, Tape and Reel Information - continued



## Physical Dimension, Tape and Reel Information - continued







## **Ordering Information**

L M x	x x x	x W x	Т
Part Number LM358xx LM324xx LM2902xx LM2904xx	ESD Tolerance applicable W : 2kV None : Normal	Package type D : S.O package P : SSOP S : Mini SO	

#### Lin<u>e-up</u>

Topr	Dual/Quad	ESD	Package	Orderable Part Number
		Normal	SO Package8 (SOP-J8)	LM358DT
			TSSOP8 (TSSPO-B8)	LM358PT
	Dual		Mini SO8 (TSSOP-B8J)	LM358ST
-40°C to 85°C		2kV	SO Package8 (SOP-J8)	LM358WDT
-40 C 10 85 C		ZKV	TSSOP8 (TSSPO-B8)	LM358WPT
		Normal	SO Package14 (SOP-J14)	LM324DT
	Quad	Normai	TSSOP14 (TSSOP-B14J)	LM324PT
		2kV	SO Package14 (SOP-J14)	LM324WDT
		Normal	SO Package8 (SOP-J8)	LM2904DT
			TSSOP8 (TSSPO-B8)	LM2904PT
	Dual		Mini SO8 (TSSOP-B8J)	LM2904ST
-40°C to +125°C		2kV	SO Package8 (SOP-J8)	LM2904WDT
-40 C 10 +125 C		ZKV	TSSOP8 (TSSPO-B8)	LM2904WPT
		Normal	SO Package14 (SOP-J14)	LM2902DT
	Quad	normal	TSSOP14 (TSSOP-B14J)	LM2902PT
		2kV	SO Package14 (SOP-J14)	LM2902WDT

## Marking Diagram









SOP-J14(TOP VIEW)	
	Part Number Marking
	LOT Number
	1PIN MARK

Product Name		Package Type	Marking
	DT	SO Package8 (SOP-J8)	
	PT	TSSOP8 (TSSPO-B8)	
LM358	ST	Mini SO8 (TSSOP-B8J)	358
	WDT	SO Package8 (SOP-J8)	
	WPT	TSSOP8 (TSSPO-B8)	
	DT	SO Package14 (SOP-J14)	
LM324	PT	TSSOP14 (TSSOP-B14J)	324
WDT	WDT	SO Package14 (SOP-J14)	
	DT	SO Package8 (SOP-J8)	
	PT	TSSOP8 (TSSPO-B8)	
LM2904	ST	Mini SO8 (TSSOP-B8J)	2904
	WDT	SO Package8 (SOP-J8)	
	WPT	TSSOP8 (TSSPO-B8)	
	DT	SO Package14 (SOP-J14)	
LM2902	PT	TSSOP14 (TSSOP-B14J)	2902
	WDT	SO Package14 (SOP-J14)	]

## Land Pattern Data

		All dimensions	in mm	
PKG	Land pitch e	Land space MIE	Land length ≥{ 2	Land width b2
SO Package8 (SOP-J8) SO Package14 (SOP-J14)	1.27	3.90	1.35	0.76
TSSOP8 (TSSPO-B8) TSSOP14 (TSSOP-B14J)	0.65	4.60	1.20	0.35
Mini SO8 (TSSOP-B8J)	0.65	3.20	1.15	0.35

SOP-J8, TSSOP-B8, TSSOP-B8J, SOP-J14, TSSOP-B14J



## **Revision History**

Date	Revision	Changes
15.Jun.2015	001	New Release

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CLASSⅣ	CLASSII	CLASSⅢ	CLASSII

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  - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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  - [d] the Products are exposed to high Electrostatic
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## LM358WPT - Web Page

**Distribution Inventory** 

Part Number	LM358WPT
Package	TSSOP8
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

**ROHM Semiconductor:** 

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